



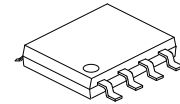
2.5V TO 6.0V MICROPOWER CMOS OP AMP

DESCRIPTION

The UTC **ULV607** is unity-gain stable operational amplifiers (op amps) with low offset voltage (950µV, maximum) and low input bias current. Performance characteristic include rail-to-rail output swing capability. These features make **ULV607** well suited for single-supply, precision, high-impedance, battery-powered applications.

FEATURES

- * Power Supply Voltage: 2.5V~6.0V
- * Low Input Offset Voltage: ±950µV (maximum)
- * Rail-to-Rail Output
- * Low Quiescent Current: 18.7µA (typical)
- * Unity-Gain Stable
- * No Phase Reversal



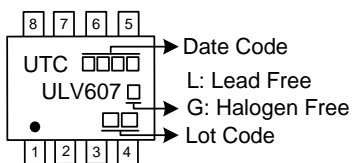
SOP-8

ORDERING INFORMATION

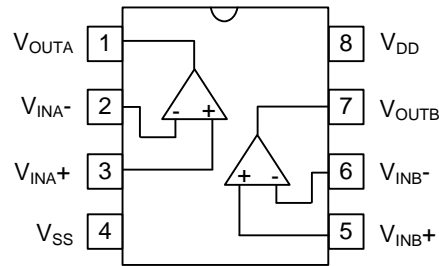
Ordering Number		Package	Packing
Lead Free	Halogen Free		
ULV607L-S08-R	ULV607G-S08-R	SOP-8	Tape Reel

<p>ULV607G-S08-R</p> <ul style="list-style-type: none"> (1) Packing Type (2) Package Type (3) Green Package 	<ul style="list-style-type: none"> (1) R: Tape Reel (2) S08: SOP-8 (3) G: Halogen Free and Lead Free, L: Lead Free
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MARKING



■ PIN CONFIGURATION



■ PIN DESCRIPTION

PIN NO.	PIN NAME	DESCRIPTION
1	V _{OUTA}	Output (op amp A)
2	V _{INA-}	Inverting Input (op amp A)
3	V _{INA+}	Non-inverting Input (op amp A)
4	V _{SS}	Negative Power Supply
5	V _{INB+}	Non-inverting Input (op amp B)
6	V _{INB-}	Inverting Input (op amp B)
7	V _{OUTB}	Output (op amp B)
8	V _{DD}	Positive Power Supply

■ ABSOLUTE MAXIMUM RATING

PARAMETER	SYMBOL	RATINGS	UNIT
Power Supply	$V_{DD}-V_{SS}$	7.0	V
Current at Input Pin	I_{IN}	± 2	mA
Analog Inputs	V_{IN+}, V_{IN-}	$V_{SS}-1.0 \sim V_{DD}+1.0$	V
All Other Inputs and Outputs		$V_{SS}-0.3 \sim V_{DD}+0.3$	V
Difference Input Voltage		$ V_{DD}-V_{SS} $	V
Output Short Circuit Current		Continuous	
Current at Output and Supply Pins		± 30	mA
Maximum Junction Temperature	T_J	+150	°C
Operating Temperature Range	T_{OPR}	-40 ~ +125	°C
Storage Temperature	T_{STG}	-65 ~ +150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL DATA

PARAMETER	SYMBOL	MIN	TYP	MAX	UNIT
Junction to Case	θ_{JA}		150		°C/W

■ DC ELECTRICAL CHARACTERISTICS

Unless otherwise indicated, $V_{DD}=+2.5V \sim +5.5V$, $V_{SS}=GND$, $T_A=+25^\circ C$, $V_{CM}=V_{DD}/2$, $V_{OUT} \approx V_{DD}/2$, $V_L=V_{DD}/2$, $R_L=100k\Omega$ to V_L (refer to Figure 1 and Figure 2).

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Input Offset						
Input Offset Voltage	V_{OS}		-950		+950	μV
Power Supply Rejection Ratio	PSRR		80	93		dB
Input Bias Current and Impedance						
Input Bias Current	I_B			1		pA
Input Offset Bias Current	I_{OS}			1		pA
Common Mode Input Impedance	Z_{CM}			$10^{13} 6$		ΩpF
Differential Input Impedance	Z_{DIFF}			$10^{13} 6$		ΩpF
Common Mode						
Common Mode Input Range	V_{CMR}	CMRR ≥ 75 dB	$V_{SS}-0.3$		$V_{DD}-1.1$	V
Common Mode Rejection Ratio	CMRR	$V_{DD}=5V, V_{CM}=-0.3V \sim 3.9V$	70	91		dB
Open-Loop Gain						
DC Open-Loop Gain (Large-signal)	A_{OL}	$R=25k\Omega$ to V_L , $V_{OUT}=50mV$ to $V_{DD}-50mV$	72	121		dB
DC Open-Loop Gain (Large-signal)	A_{OL}	$R=5k\Omega$ to V_L , $V_{OUT}=0.1V$ to $V_{DD}-0.1V$	70	118		dB
Output						
Maximum Output Voltage Swing	V_{OL}, V_{OH}	$R_L=25k\Omega$ to V_L , 0.5V input overdrive	$V_{SS}+15$		$V_{DD}-20$	mV
		$R_L=5k\Omega$ to V_L , 0.5V input overdrive	$V_{SS}+45$		$V_{DD}-60$	mV
Linear Output Voltage Range	V_{OUT}	$R_L=25k\Omega$ to V_L , $A_{OL} \geq 105dB$	$V_{SS}+50$		$V_{DD}-50$	mV
		$R_L=5k\Omega$ to V_L , $A_{OL} \geq 100dB$	$V_{SS}+100$		$V_{DD}-100$	mV
Output Short Circuit Current	I_{SC}	$V_{DD}=2.5V$		7		mA
		$V_{DD}=5.5V$		17		mA
Power Supply						
Supply Voltage	V_{DD}		2.5		6.0	V
Quiescent Current per Amplifier	I_Q	$I_O=0$		18.7	50	μA

■ AC ELECTRICAL CHARACTERISTICS

Unless otherwise indicated, $V_{DD}=+2.5V\sim+5.5V$, $V_{SS}=GND$, $T_A=+25^\circ C$, $V_{CM}=V_{DD}/2$, $V_{OUT}\approx V_{DD}/2$, $V_L=V_{DD}/2$, $R_L=100k\Omega$ to V_L and $C_L=60pF$ (refer to Figure 1 and Figure 2).

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Gain Bandwidth Product	GBWP			155		kHz
Phase Margin	PM	$G=+1V/V$		62		°
Slew Rate	SR			0.08		V/ μs
Noise						
Input Noise Voltage	E_{ni}	$f=0.1Hz\sim 10Hz$		2.8		$\mu VP-P$
Input Noise Voltage Density	e_{ni}	$f=1kHz$		38		nV/\sqrt{Hz}
Input Noise Current Density	i_{ni}	$f=1kHz$		3		fA/\sqrt{Hz}

■ TEST CIRCUIT

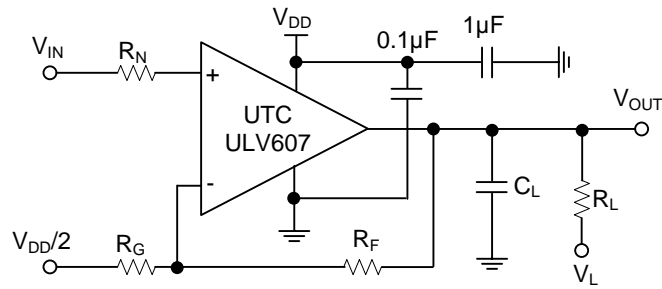


Figure 1. AC and DC Test Circuit for Most Non-Inverting Gain Conditions.

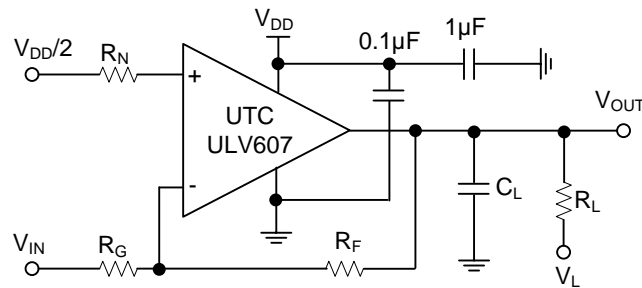
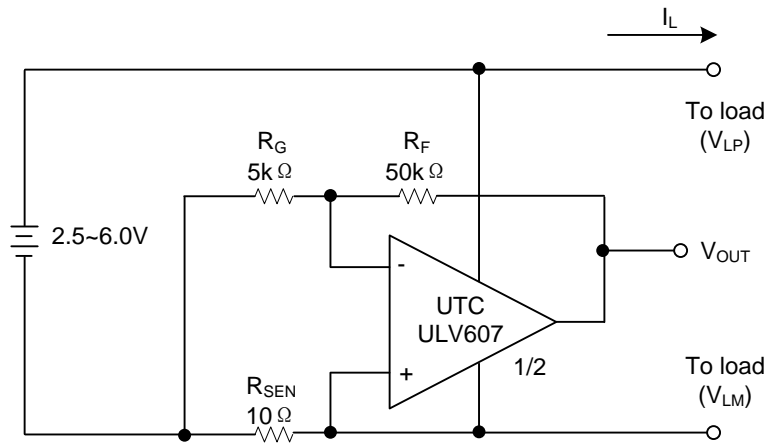


Figure 2. AC and DC Test Circuit for Most Inverting Gain Conditions.

■ TYPICAL APPLICATION CIRCUIT



Low-Side Battery Current Sensor

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